NSN 5962-01-435-5813

Digital Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-435-5813

Maximum Power Dissipation Rating:
500.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
C-17a acft
Features Provided:
3-state output
Inclosure Configuration:
Leaded chip carrier
Output Logic Form:
Bipolar metal-oxide semiconductor
Design Function And Quantity:
8 buffer, tri-state and 8 driver
Current Rating Per Characteristic:
96.00 milliamperes peak forward surge current horsepower metric
Product Name:
Microcircuit, digital, advanced bipolar cmos, octal buffer/driver with three-state outputs, ttl compatible inputs, monolithic silicon
Voltage Rating And Type Per Characteristic:
5.0 volts power source
Special Features:
Ttl compatiable inputs, advanced bicmos
Terminal Type And Quantity:
20 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A458a0